

Spécialité de Master « Optique, Matière, Paris »

Stage de recherche (4 mois minimum, à partir de début mars)

Proposition de stage (ne pas dépasser 1 page)

Date de la proposition : 21 septembre 2018

Responsable du stage / internship supervisor:	
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Nom du Laboratoire / laboratory name: Laboratoire Interdisciplinaire de Physique (LIPhy)	
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Lieu du stage / internship place: GRENOBLE	

Titre du stage / internship title: Laser dynamics: laser line width broadening measurements
Résumé / summary
<p>Context: We propose an original method for the measurement of the Henry factor (α_H) coupling the refraction index and the gain of the amplification medium of a semiconductor laser. This factor was introduced to account for the laser linewidth broadening ($1 + \alpha_H^2$) with respect to the fundamental limit [1] given by the spontaneous emission rate of the gain medium which perturbs the laser field maintained by stimulated emission (Schawlow-Townes equation). Even though the dynamics of diode lasers has been investigated during a few decades, for quantum cascade lasers (QCLs) investigations of their linewidth are not many and results are sometimes contradictory. We propose an original method of measurement which should allow a better understanding of the dynamics of these lasers.</p> <p>Method: The technique which will be applied consists in the observation of the laser response to optical feedback, in a regime of weak feedback levels [2]. Optical feedback induces a change of the emission frequency and power. One can show that a measurement of both these parameters allows to deduce the α_H coefficient. The originality of this technique rests on the use of a resonant optical cavity in a V-shaped geometry (see picture below).</p> <p>Objective: The goal is the determination of the Henry factor for different types of semiconductor lasers: Diode lasers in the near infrared ($\sim 2\mu\text{m}$) to obtain results to be compared to previously published values; then in particular QCLs and ICLs (intra-band cascade lasers) in the mid infrared (around $5\mu\text{m}$) which have become commercially available only these last few years.</p> <p>Expected skills : The candidate will have good knowledge of laser optics and an interest in instrumental developments and modeling.</p>
Master 1 or Master 2 internship: position available from February 2019, duration of 2 to 6 months. PhD continuation possible (well suited).
Supervisor: irene.ventrillard@univ-grenoble-alpes.fr https://www-liphy.ujf-grenoble.fr/-LAME-
[1] C. H. Henry, "Theory of the Linewidth of Semiconductor Lasers," <i>IEEE J. Quantum Electron.</i> , vol. 18, no. 2, pp. 259–264, 1982.
[2] C. Szwarz, E. Lacot, and O. Hugon, "Large linewidth-enhancement factor in a microchip laser," <i>Phys. Rev. A - At. Mol. Opt. Phys.</i> , vol. 70, no. 3, pp. 4–7, 2004.
[3] J. Morville, S. Kassi, M. Chenevier, and D. Romanini, "Fast, low-noise, mode-by-mode, cavity-enhanced absorption spectroscopy by diode-laser self-locking," <i>Appl. Phys. B</i> , vol. 80, no. 8, pp. 1027–1038, May 2005.

Ce stage pourra-t-il se prolonger en thèse ? Possibility of a PhD ? : YES			
Si oui, financement de thèse envisagé/ financial support for the PhD:			
Lumière, Matière, Interactions	X	Lasers, Optique, Matière	X